## NSN 5961-01-221-7975

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-221-7975 **Inclosure Material:** Glass and metal **Overall Length:** 7.625 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-8 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 1.062 inches **Thread Size:** 0.375 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 reverse voltage, peak **Current Rating Per Characteristic:** 125.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 190.0 degrees celsius ambient air **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: